

VS-MBR6045WTPbF, VS-MBR6045WT-N3

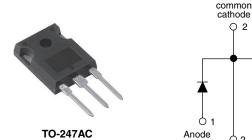
Vishay Semiconductors

Schottky Rectifier, 2 x 30 A

Base

Common cathode

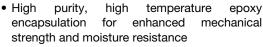
Anode



PRODUCT SUMMARY							
Package	TO-247AC						
I _{F(AV)}	2 x 30 A						
V_{R}	45 V						
V _F at I _F	0.55 V						
I _{RM} max.	150 mA at 125 °C						
T_J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	27 mJ						
	•						

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-MBR6045WT... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	OL CHARACTERISTICS VALUES UNI								
I _{F(AV)}	Rectangular waveform	60	Α						
V _{RRM}		45	V						
I _{FSM}	t _p = 5 μs sine	2900	Α						
V _F	30 Apk, T _J = 125 °C (per leg)	0.55	V						
T _J		- 55 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBR6045WTPbF	VS-MBR6045WT-N3	UNITS					
Maximum DC reverse voltage	V _R	45	45	V					
Maximum working peak reverse voltage	V _{RWM}	40	45	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS			
Maximum average	per leg			_	30			
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T_C = 122 °C, rectangular waveform		60	Α		
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		l=	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	2900			
		IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	360			
Non-repetitive avalanche ene	rgy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 4 A, L = 3.4 mH		27	mJ		
Repetitive avalanche current p	per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		6	Α		



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
Maximum forward voltage drop per leg See fig. 1		30 A	T _{.1} = 25 °C	0.62	V		
	V _{FM} (1)	60 A	11=23 0	0.75			
		30 A	T _J = 125 °C	0.55			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1	mA		
See fig. 2		T _J = 125 °C	VR = nated VR	150			
Threshold voltage	V _{F(TO)}	T - T movimum		0.27	٧		
Forward slope resistance	r _t	$T_J = T_J$ maximum		7.3	mΩ		
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range	1400	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 m	7.5	nΗ			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 150	°C			
Maximum thermal resistance, junction to case per leg		D	DC operation See fig. 4	1.0 0.5 °C/W				
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation					
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.24				
Approximate weight				6	g			
Approximate weight				0.21	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque —	maximum			12 (10)	(lbf \cdot in)			
Marking device			Case style TO-247AC (JEDEC)	MBR60	045WT			

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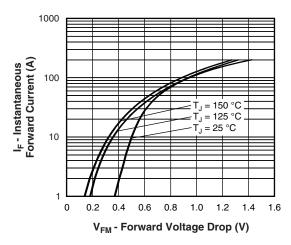


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

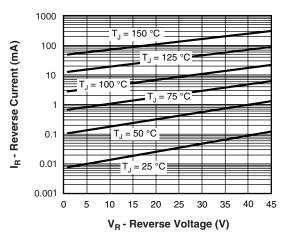


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

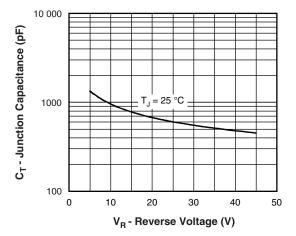


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

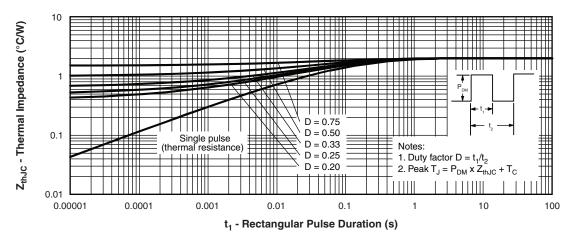


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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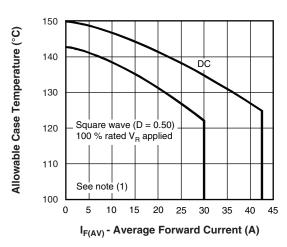


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

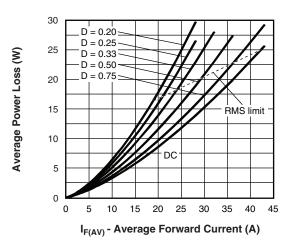


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

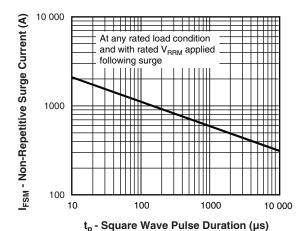


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

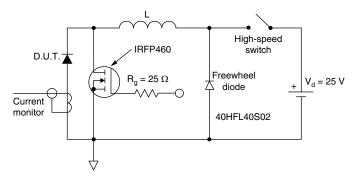


Fig. 8 - Unclamped Inductive Test Circuit

Note

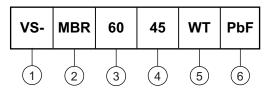
(1) Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 100 % rated V_R

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Schottky MBR series

Current rating (60 = 60 A)

Voltage rating (45 = 45 V)

5 - Circuit configuration:

6 Center tap (dual) TO-247

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBR6045WTPbF	25	500	Antistatic plastic tube						
VS-MBR6045WT-N3	25	500	Antistatic plastic tube						

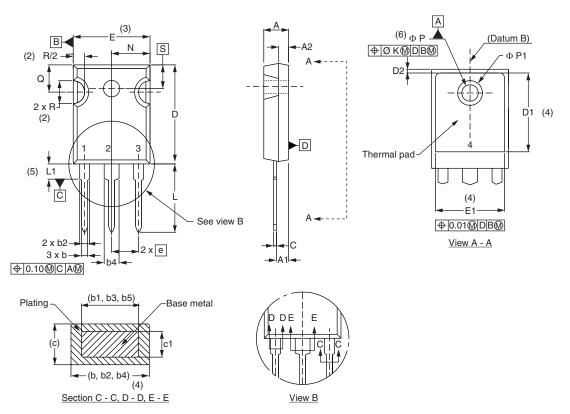
LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95223				
Part marking information	TO-247AC PbF	www.vishay.com/doc?95226				
	TO-247AC -N3	www.vishay.com/doc?95007				



Vishay Semiconductors

TO-247

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		METERS INCHES		NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			Е	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØΚ	2.	54	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			Ν	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ØΡ	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}\,$ Outline conforms to JEDEC® outline TO-247 with exception of dimension c



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